

### General Features

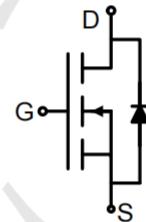
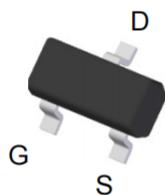
- $V_{DS} = 100V, I_D = 3.5A$
- $R_{DS(ON)} < 130m\Omega @ V_{GS}=10V$  (96m $\Omega$  Typ)
- $R_{DS(ON)} < 180m\Omega @ V_{GS}=4.5V$  (140m $\Omega$  Typ)

### Application

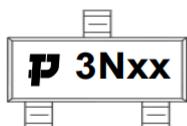
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable
- Logic Level Shift

### Package and Pin Configuration

SOT23



### Marking:



“P” is TECHPUBLIC LOGO  
“3N” is Part number,fixed  
“xx” is internal code

### Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	3.5	A
Drain Current-Pulsed (Note 1)	$I_{DM}$	20	A
Maximum Power Dissipation	$P_D$	1.5	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 175	°C

### Thermal Characteristic

Thermal Resistance,Junction-to-Ambient (Note 2)	$R_{\theta JA}$	100	°C/W
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**ZVN3310FTA**

**100V 3.5A N-Channel MOSFET**

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**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	100	-	-	V
Zero Gate Voltage Drain Current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}}=100\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage Current	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}}=\pm20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	$\pm100$	nA
<b>On Characteristics</b> <small>(Note 3)</small>						
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	1.0	1.5	2.0	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(ON)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=3\text{A}$	-	96	130	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=1\text{A}$	-	140	180	
Forward Transconductance	$\text{g}_{\text{FS}}$	$\text{V}_{\text{DS}}=5\text{V}, \text{I}_D=3\text{A}$	-	5	-	S
<b>Dynamic Characteristics</b> <small>(Note 4)</small>						
Input Capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}}=50\text{V}, \text{V}_{\text{GS}}=0\text{V},$ $F=1.0\text{MHz}$	-	650	-	PF
Output Capacitance	$\text{C}_{\text{oss}}$		-	24	-	PF
Reverse Transfer Capacitance	$\text{C}_{\text{rss}}$		-	20	-	PF
<b>Switching Characteristics</b> <small>(Note 4)</small>						
Turn-on Delay Time	$t_{\text{d(on)}}$	$\text{V}_{\text{DD}}=50\text{V}, \text{R}_L=19\Omega$ $\text{V}_{\text{GS}}=10\text{V}, \text{R}_G=3\Omega$	-	6	-	nS
Turn-on Rise Time	$t_r$		-	4	-	nS
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	20	-	nS
Turn-Off Fall Time	$t_f$		-	4	-	nS
Total Gate Charge	$\text{Q}_g$	$\text{V}_{\text{DS}}=50\text{V}, \text{I}_D=3\text{A},$ $\text{V}_{\text{GS}}=10\text{V}$	-	20	-	nC
Gate-Source Charge	$\text{Q}_{\text{gs}}$		-	2.1	-	nC
Gate-Drain Charge	$\text{Q}_{\text{gd}}$		-	3.3	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <small>(Note 3)</small>	$\text{V}_{\text{SD}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_S=3\text{A}$	-	-	1.2	V
Diode Forward Current <small>(Note 2)</small>	$\text{I}_S$			3.5		A

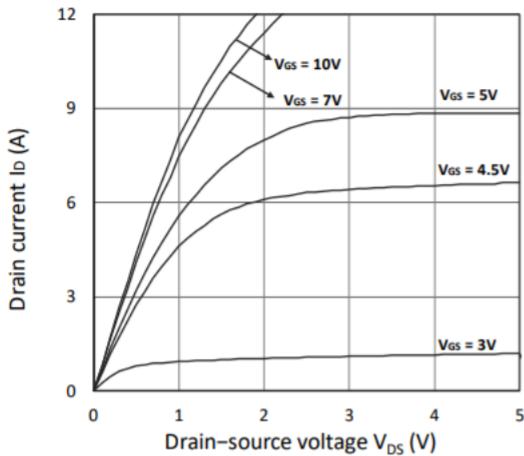


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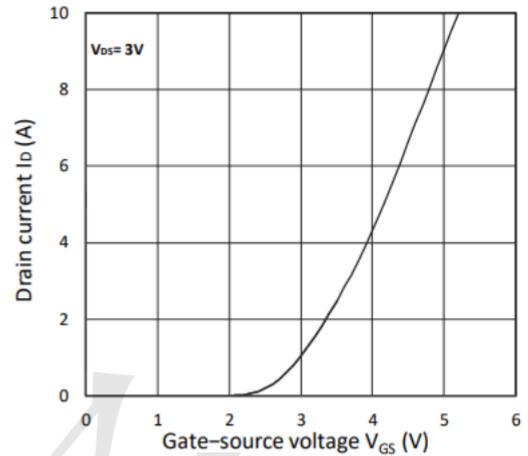
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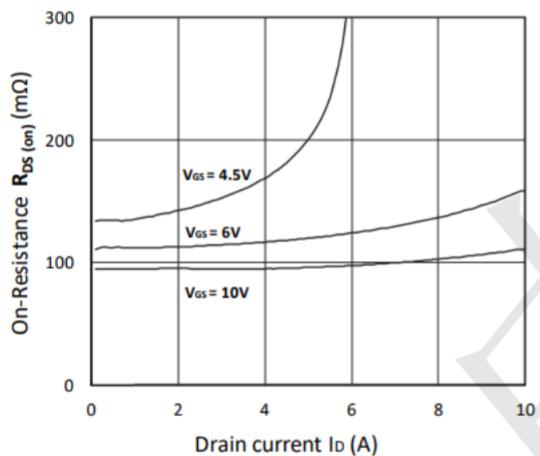
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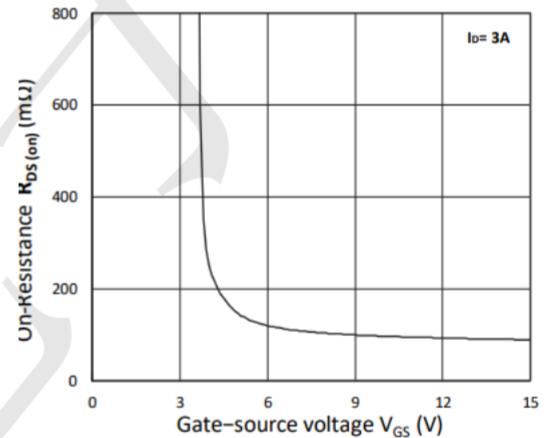
**Figure 1. Output Characteristics**



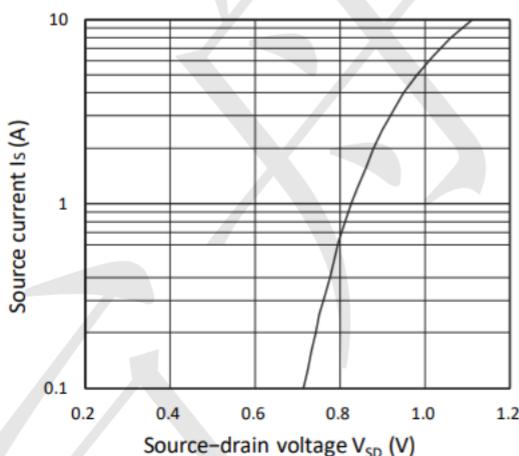
**Figure 2. Transfer Characteristics**



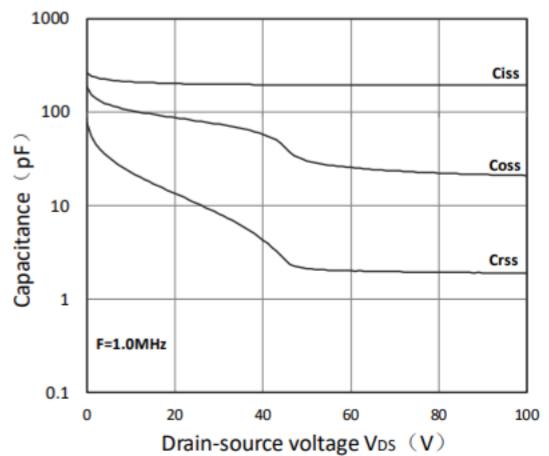
**Figure 3. R<sub>D(on)</sub> VS. I<sub>D</sub>**



**Figure 4. R<sub>D(on)</sub> VS. V<sub>G</sub>**



**Figure 5. I<sub>S</sub> VS. V<sub>SD</sub>**



**Figure 6. Capacitance Characteristics**



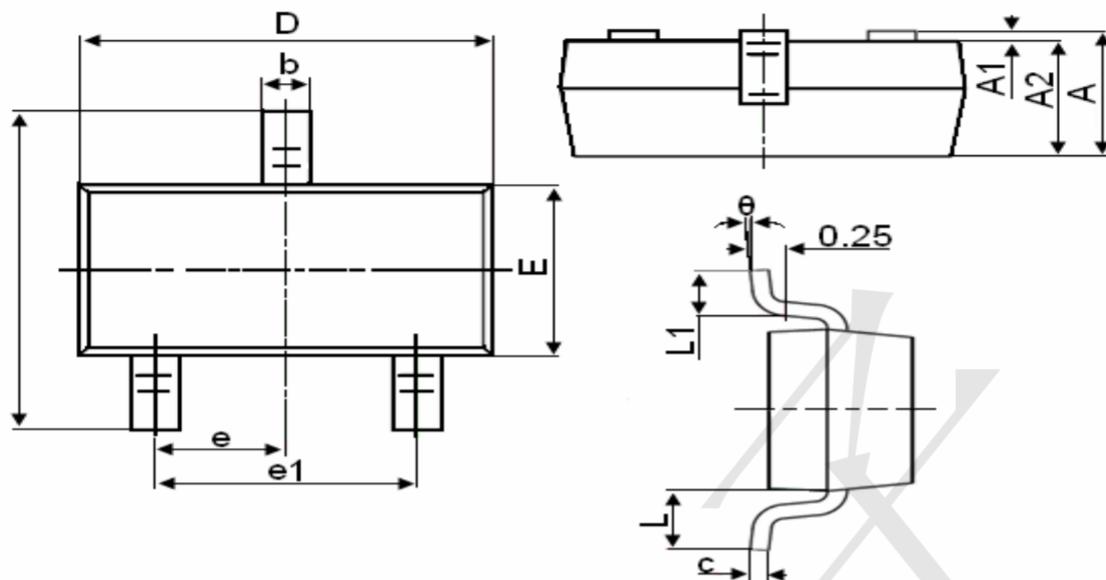
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### Package Outline Dimensions (SOT-23)



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

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